

KSC2310

High Voltage Power Amplifier

- Collector-Base Voltage: V_{CBO}=200V
 Current Gain Bandwidth Product: f_T=100MHz



1. Emitter 2. Collector 3. Base

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

| Symbol | Parameter | Ratings | Units |
|------------------|-----------------------------|-----------|-------|
| V_{CBO} | Collector-Base Voltage | 200 | V |
| V _{CEO} | Collector-Emitter Voltage | 150 | V |
| V _{EBO} | Emitter-Base Voltage | 5 | V |
| I _C | Collector Current | 50 | mA |
| P _C | Collector Power Dissipation | 800 | mW |
| T _J | Junction Temperature | 150 | °C |
| T _{STG} | Storage Temperature | -55 ~ 150 | °C |

Electrical Characteristics T_a =25°C unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Units |
|-----------------------|--|---|------|------|------|-------|
| BV _{CBO} | Collector-Base Breakdown Voltage | $I_C=100\mu A, I_E=0$ | 200 | | | V |
| BV _{CEO} | Collector-Emitter Breakdown Voltage I _C =5mA, I _B =0 | | 150 | | | V |
| BV _{EBO} | Emitter-Base Breakdown Voltage | $I_E=100\mu A, I_C=0$ | 5 | | | V |
| I _{CBO} | Collector Cut-off Current | V _{CB} =200V, I _E =0 | | | 0.1 | μΑ |
| h _{FE} | DC Current Gain | V _{CE} =5V, I _C =10mA | 40 | | 240 | |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage | I _C =10mA, I _B =1mA | | | 0.5 | V |
| f _T | Current Gain Bandwidth Product | V _{CE} =30V, I _C =10mA | | 100 | | MHz |
| C _{ob} | Output Capacitance | V _{CB} =10V, I _E =0, f=1MHz | | 3.5 | 5 | pF |

h_{FE} Classification

| Classification | R | 0 | Y |
|-----------------|---------|----------|-----------|
| h _{FE} | 40 ~ 80 | 70 ~ 140 | 120 ~ 240 |

Typical Characteristics

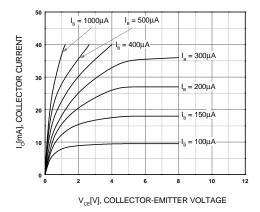


Figure 1. Static Characteristic

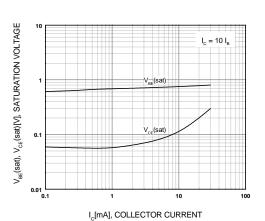


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

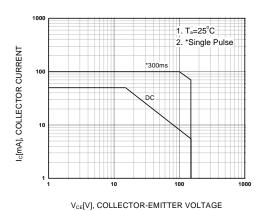
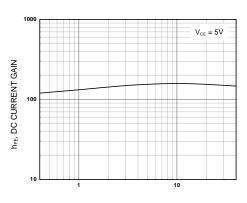


Figure 5. Safe Operating Area



 $I_{\text{c}}[\text{mA}]$, COLLECTOR CURRENT

Figure 2. DC current Gain

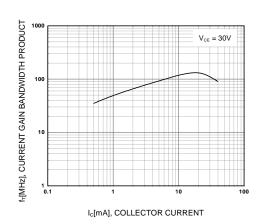


Figure 4. Current Gain Bandwidth Product

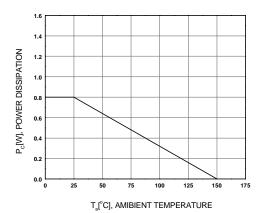
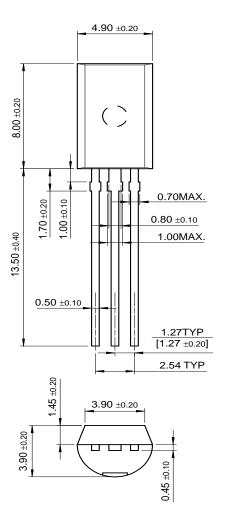


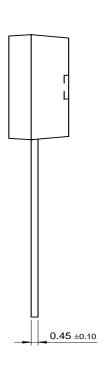
Figure 6. Power Derating

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Package Dimensions

TO-92L





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